NSN 5961-01-537-6720

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-537-6720 **Inclosure Material:** Glass **Overall Length:** 1.650 inches **End Application:** 0a-923 (v) /g, operations group fixed **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 5.8 working peak reverse voltage and 7.1 breakdown voltage, dc **Current Rating Per Characteristic:** 10.00 milliamperes forward current, average peak **Product Name:** Semiconductor device assembly **Special Features:** Semiconductor device diode 1n5629a, 2 terminal lug crimp type, insulation slvg elec. Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0